Unit: mm

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

# 2SC6076

Power Amplifier Applications
Power Switching Applications

Low collector saturation voltage: VCE (sat) = 0.5 V (max) (IC = 1A) High-speed switching:  $t_{stg}$  = 0.4  $\mu s$  (typ)

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit	
Collector-base voltage	$V_{CBO}$	160	V	
Collector-emitter voltage	V <sub>CEX</sub>	160	V	
Collector-emitter voltage		V <sub>CEO</sub>	80	V
Emitter-base voltage	V <sub>EBO</sub>	9	V	
Collector current	DC	IC	3	Α
	Pulse	I <sub>CP</sub>	5	Α
Base current	ΙΒ	1.5	Α	
Collector power dissipation	Tc = 25°C	PC	10	W
Junction temperature	Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 <b>~</b> 150	°C

1.5±0.2 5.2±0.2 0.6MAX 5.5±0.2  $9.5 \pm 0.3$ 1.1±0.2 0.8MAX 0.6±0.15 2.3±0.15 2.3±0.15 1: BASE 2 : COLLECT 3 : EMITTER COLLECTOR (HEAT SINK) **JEDEC** JEITA **TOSHIBA** 2-7J1A

Weight:0.36g(typ)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

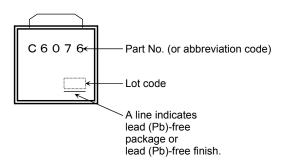
temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

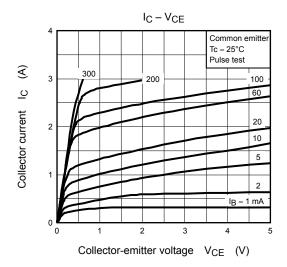
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

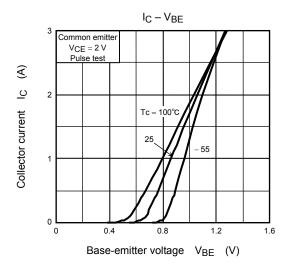
## Electrical Characteristics (Ta = 25°C)

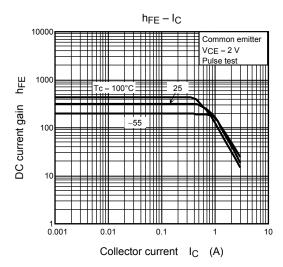
Characteristic		Symbol	Test Conditions	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	V <sub>CB</sub> = 160 V, I <sub>E</sub> = 0	_	_	1.0	μΑ
Emitter cut-off current		I <sub>EBO</sub>	V <sub>EB</sub> = 9 V, I <sub>C</sub> = 0	-	_	1.0	μА
Collector-emitter breakdown voltage		V (BR) CEO	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	80	_	_	V
DC current gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 1 mA	150	_	_	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 0.5 A	180	_	450	
		h <sub>FE</sub> (3)	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 1 A	100	_	_	
Collector emitter saturation voltage		V <sub>CE</sub> (sat) (1)	I <sub>C</sub> = 0.5 A, I <sub>B</sub> = 50 mA	_	_	0.3	V
		V <sub>CE</sub> (sat) (2)	I <sub>C</sub> = 1 A, I <sub>B</sub> = 100 mA	_	_	0.5	V
Base-emitter saturation voltage		V <sub>BE</sub> (sat)	I <sub>C</sub> = 1 A, I <sub>B</sub> = 100 mA	_	_	1.5	V
Transition frequency		f <sub>T</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 0.5 A	_	150	_	$MH_Z$
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0,f = 1MH <sub>Z</sub>	_	14	_	pF
Switching time	Rise time	t <sub>r</sub>	20 $\mu$ s Input $\stackrel{ B1}{\longrightarrow}$ Output $\stackrel{ B1}{\longrightarrow}$ $\stackrel{ B1}{\longrightarrow}$ $\stackrel{ B2}{\longrightarrow}$ $\stackrel{ B2}{\longrightarrow}$ $\stackrel{ B2}{\longrightarrow}$ $\stackrel{ B2}{\longrightarrow}$ $\stackrel{ B1}{\longrightarrow}$ $\stackrel{ B2}{\longrightarrow}$ $\stackrel{ B2}{\longrightarrow}$ $\stackrel{ B2}{\longrightarrow}$ $\stackrel{ B1}{\longrightarrow}$ $\stackrel{ B2}{\longrightarrow}$ $\stackrel{ B2}{$	_	0.05	_	
	Storage time	t <sub>stg</sub>		_	0.4	_	μS
	Fall time	t <sub>f</sub>		ı	0.15	_	

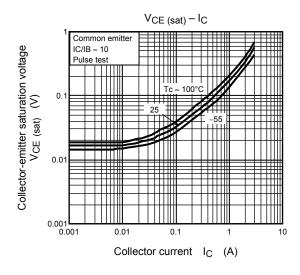
## Marking

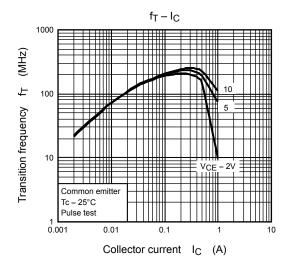


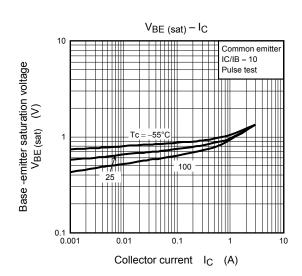


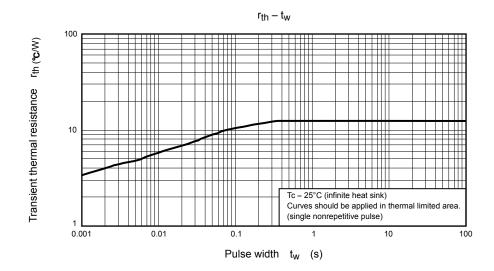


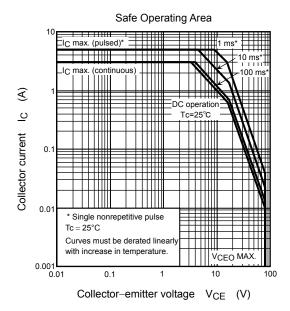












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